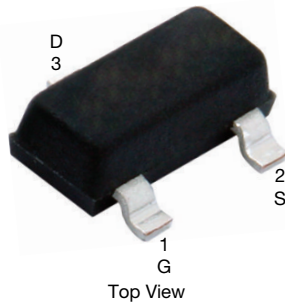


Automotive N-Channel 60 V (D-S) 175 °C MOSFET

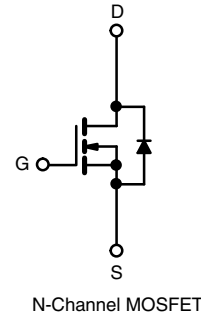
SOT-23 (TO-236)



FEATURES

- TrenchFET® Power MOSFET
- AEC-Q101 Qualified
- 100 % R_G and UIS Tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

AUTOMOTIVE GRADE


RoHS
 COMPLIANT
 HALOGEN
FREE

Marking Code: 9RYXX

PRODUCT SUMMARY	
V _{DS} (V)	60
R _{DS(on)} (Ω) at V _{GS} = 10 V	0.150
R _{DS(on)} (Ω) at V _{GS} = 4.5 V	0.164
I _D (A)	2.3
Configuration	Single

ORDERING INFORMATION	
Package	SOT-23
Lead (Pb)-free and halogen-free	SQ2308FES-T1_GE3

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)				
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V _{DS}	60	V
Gate-source voltage		V _{GS}	± 20	
Continuous drain current	T _C = 25 °C	I _D	2.3	A
	T _C = 125 °C		1.3	
Continuous source current (diode conduction)		I _S	2.4	
Pulsed drain current ^a		I _{DM}	9	
Single pulse avalanche current	L = 0.1 mH	I _{AS}	7	
Single pulse avalanche energy		E _{AS}	2.5	mJ
Maximum power dissipation	T _C = 25 °C	P _D	2	W
	T _C = 125 °C		0.6	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount ^b	R _{thJA}	120	°C/W
Junction-to-foot (drain)		R _{thJF}	80	

Notes

- Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %
- When mounted on 1" square PCB (FR-4 material)



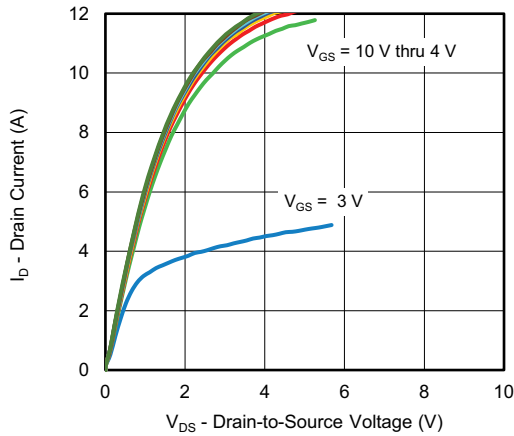
SPECIFICATIONS (T _C = 25 °C, unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX. UNIT
Static						
Drain-source breakdown voltage	V _{DS}	V _{GS} = 0, I _D = 250 μA		60	-	- V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA		1.5	2.0	2.5 V
Gate-source leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 20 V		-	-	± 100 nA
Zero gate voltage drain current	I _{DSS}	V _{GS} = 0 V	V _{DS} = 60 V	-	-	1 μA
		V _{GS} = 0 V	V _{DS} = 60 V, T _J = 125 °C	-	-	50 μA
		V _{GS} = 0 V	V _{DS} = 60 V, T _J = 175 °C	-	-	150 μA
On-state drain current ^a	I _{D(on)}	V _{GS} = 10 V	V _{DS} ≥ 5 V	10	-	- A
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 2.3 A	-	0.135	0.150 Ω
		V _{GS} = 10 V	I _D = 2.3 A, T _J = 125 °C	-	-	0.272 Ω
		V _{GS} = 10 V	I _D = 2.3 A, T _J = 175 °C	-	-	0.344 Ω
		V _{GS} = 4.5 V	I _D = 2.1 A	-	0.145	0.164 Ω
Forward Transconductance ^b	g _{fs}	V _{DS} = 15 V, I _D = 2.3 A		-	8	- S
Dynamic ^b						
Input capacitance	C _{iss}	V _{GS} = 0 V	V _{DS} = 30 V, f = 1 MHz	-	170	205 pF
Output capacitance	C _{oss}			-	25	28 pF
Reverse transfer capacitance	C _{rss}			-	13	18 pF
Total gate charge ^c	Q _g	V _{GS} = 10 V	V _{DS} = 30 V, I _D = 2 A	-	3.6	5.3 nC
Gate-source charge ^c	Q _{gs}			-	0.7	- nC
Gate-drain charge ^c	Q _{gd}			-	0.6	- nC
Gate resistance	R _g	f = 1 MHz		2.9	5.84	9 Ω
Turn-on delay time ^c	t _{d(on)}	V _{DD} = 30 V, R _L = 15 Ω I _D ≅ 2 A, V _{GEN} = 10 V, R _g = 1 Ω		-	5	6 ns
Rise time ^c	t _r			-	3	13 ns
Turn-off delay time ^c	t _{d(off)}			-	10	17 ns
Fall time ^c	t _f			-	2	18 ns
Source-Drain Diode Ratings and Characteristics ^b						
Pulsed current ^a	I _{SM}			-	-	9 A
Forward voltage	V _{SD}	I _F = 1.6 A, V _{GS} = 0		-	0.82	1.2 V
Body diode reverse recovery time	t _{rr}	I _F = 2 A, di/dt = 100 A/μs		-	13	26 ns
Body diode reverse recovery charge	Q _{rr}			-	8	16 nC
Reverse recovery fall time	t _a			-	9	- ns
Reverse recovery rise time	t _b			-	4	- ns
Body diode peak reverse recovery current	I _{RM(REC)}			-	-1.25	- A

Notes

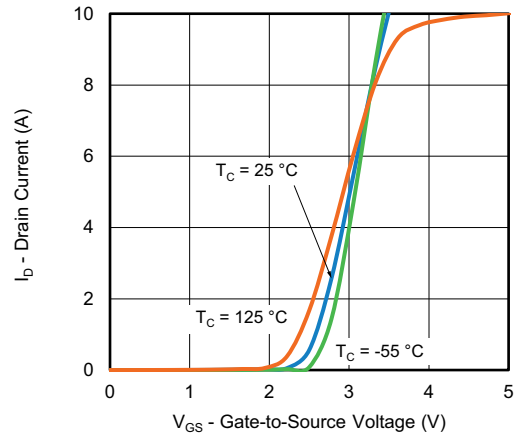
- a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

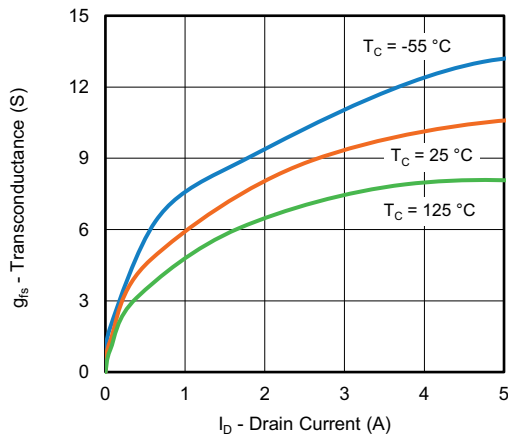
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



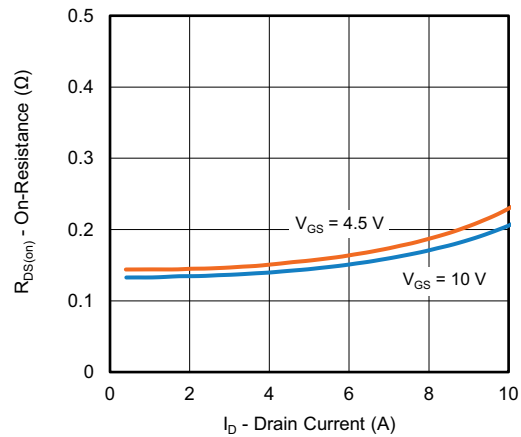
Output Characteristics



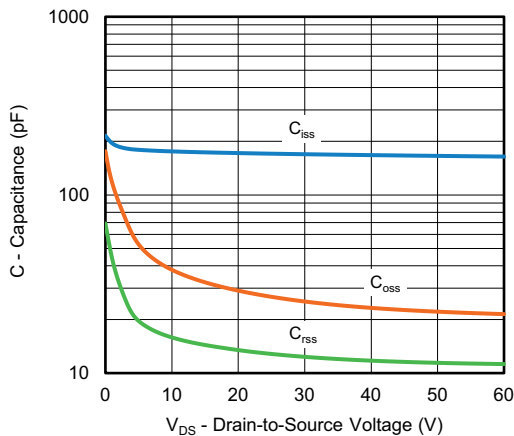
Transfer Characteristics



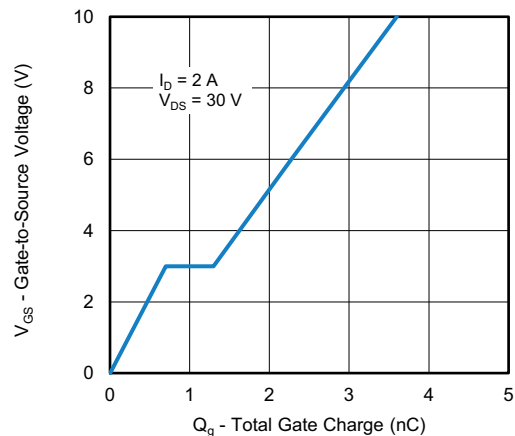
Transconductance



On-Resistance vs. Drain Current



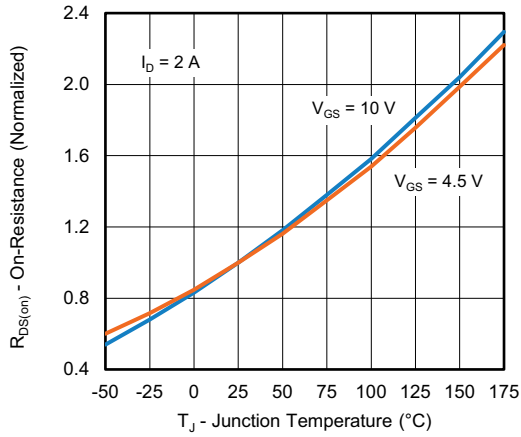
Capacitance



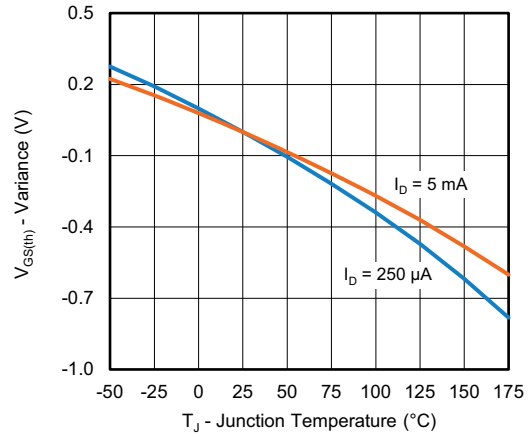
Gate Charge



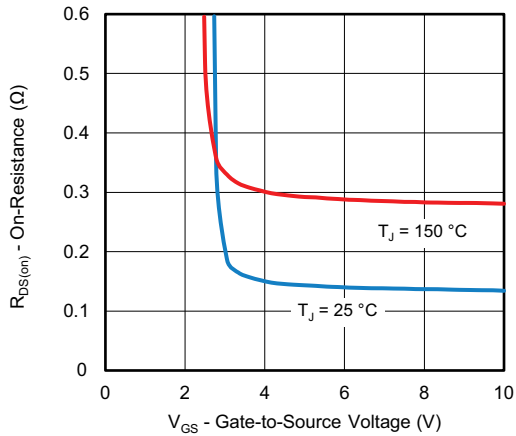
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



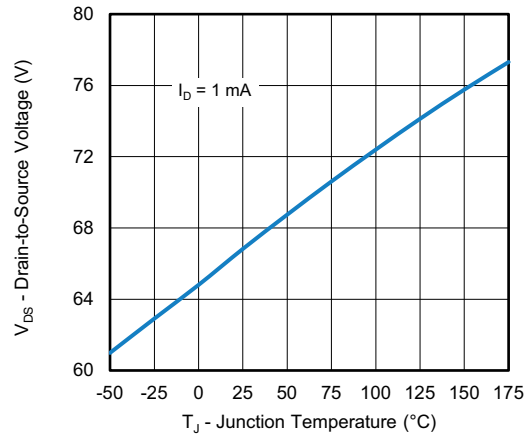
On-Resistance vs. Junction Temperature



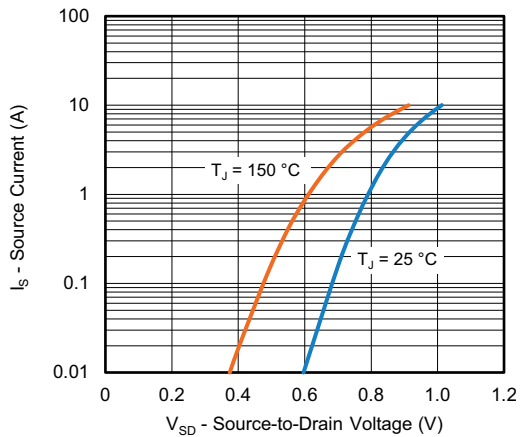
Threshold Voltage



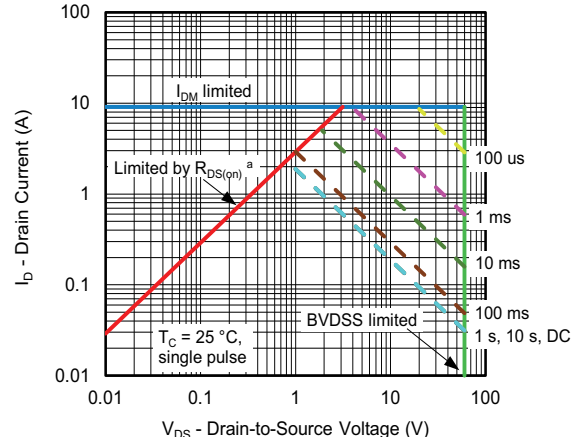
On-Resistance vs. Gate-to-Source Voltage



Drain Source Breakdown vs. Junction Temperature



Source Drain Diode Forward Voltage



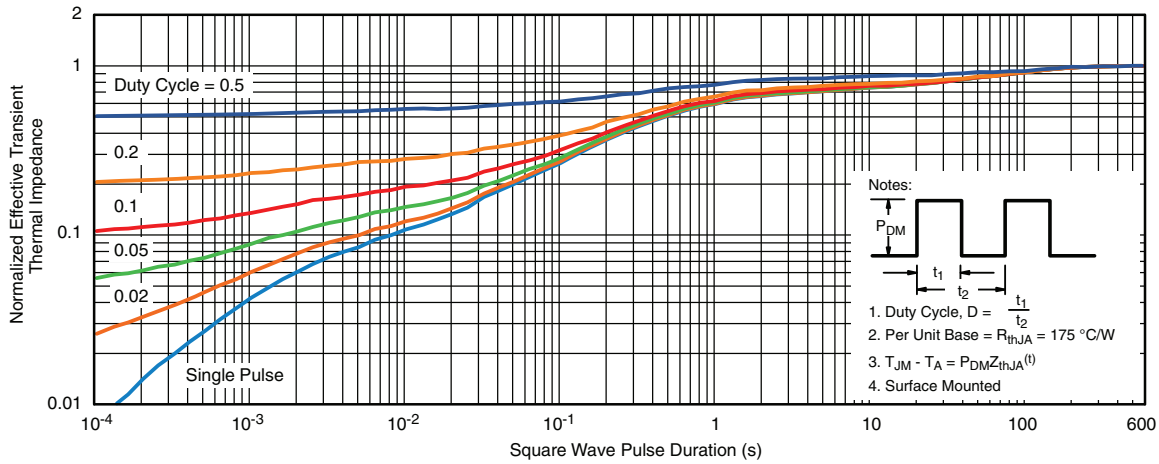
Safe Operating Area

Note

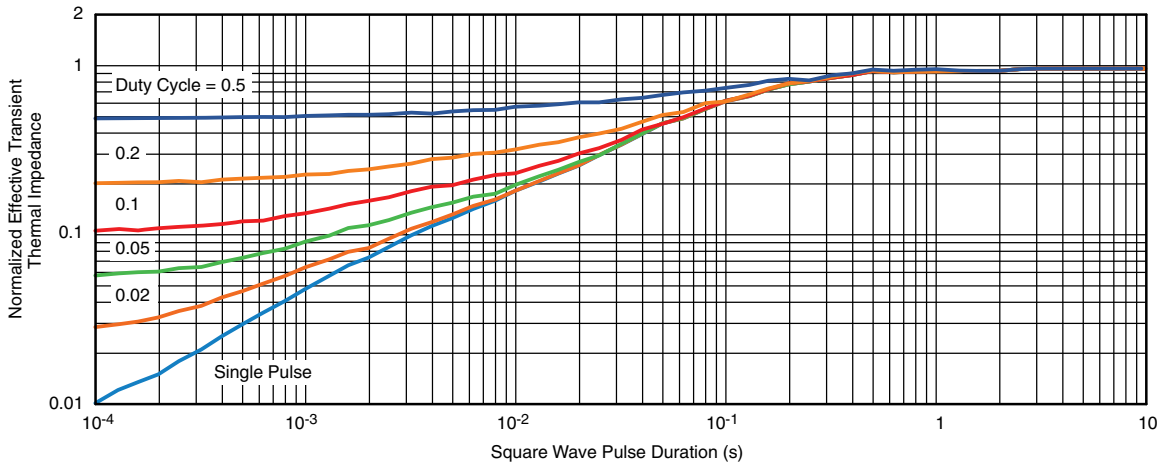
a. $V_{GS} >$ minimum V_{GS} at which $R_{DS(on)}$ is specified



THERMAL RATINGS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient ($25\text{ }^\circ\text{C}$)
 - Normalized Transient Thermal Impedance Junction-to-Foot ($25\text{ }^\circ\text{C}$)
- are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

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